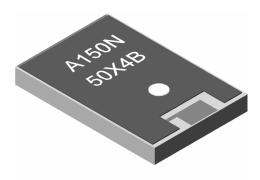




Model A150N50X4B





Features:

- **RoHS Compliant**
- 150 Watts
- DC 2.7 GHz
- **AIN Ceramic**
- **Non-Nichrome Resistive Element**
- Low VSWR
- 100% Tested



Chip Termination 150 Watts, 50Ω

Description

The A150N50X4B is high performance Aluminum Nitride (AIN) chip termination intended as a cost competitive alternative to Beryllium Oxide (BeO). The termination is well suited to all cellular frequency bands such as; AMPS, GSM, DCS, PCS, PHS and UMTS. The high power handling makes the part ideal for terminating circulators, and for use in power combiners. The termination is also RoHS compliant!

General Specifications

Resistive Element Thick film **Substrate AIN Ceramic**

Terminal Finish Matte Tin over Nickel Barrier

Operating -55 to +200°C (see de rating chart)

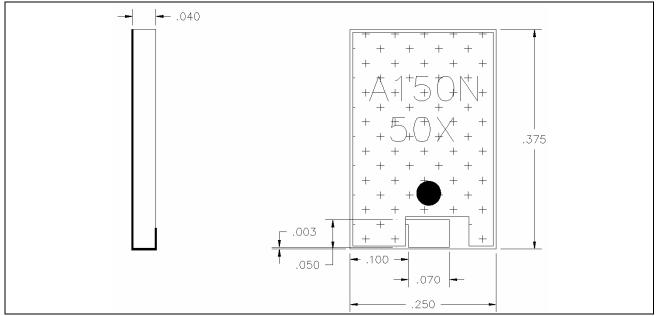
Temperature Tolerance is ±0.010", unless otherwise specified. Designed to meet of exceed applicable portions of MIL-E-5400. All dimensions in inches.

Electrical Specifications

Resistance Value: 50 Ohms. ± 2% 150 Watts Power: Frequency Range: DC - 2.7 GHz >26dB to 2.0 GHz **Return Loss** >20dB to 2.7 GHz

Specification based on unit properly installed using suggested mounting instructions and a 50 ohm nominal impedance. Specifications subject to change.

Outline Drawing



A150N50X4 (097) Rev E





Available on Tape and Reel For Pick and Place Manufacturing.

USA/Canada: (315) 432-8909 Toll Free: (800) 544-2414 +44 2392-232392 Europe:

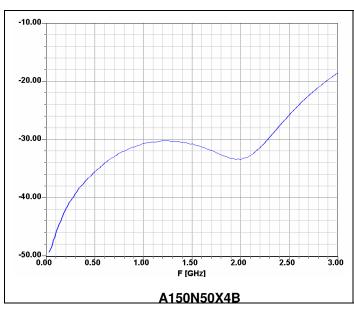


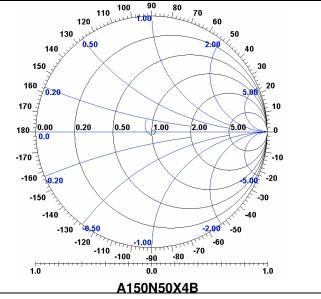
Typical Performance:





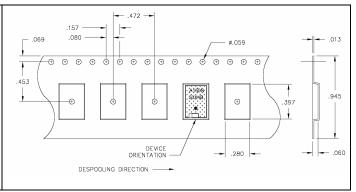




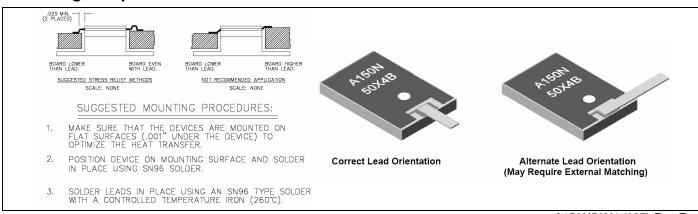


Power De-rating:

Tape & Reel:



Mounting Footprint and Procedure:



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